NSN 5961-01-226-7824

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-226-7824 **Inclosure Material:** Glass **Overall Length:** 0.180 inches **Terminal Length:** 1.000 inches **Overall Diameter:** 0.150 inches **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 600.0 reverse voltage, dc and 600.0 repetitive peak reverse voltage, peak total value and 420.0 reverse voltage, total rms **Current Rating Per Characteristic:** 25.00 amperes source cutoff current absolute and 6.00 amperes source cutoff current outside diameter and 1.00 amperes forward current, average absolute **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No